74HC40103

8-bit synchronous binary down counter

Rev. 5 — 21 April 2016

Product data sheet

1. General description

The 74HC40103 is an 8-bit synchronous down counter. It has control inputs for enabling or disabling the clock (CP), for clearing the counter to its maximum count and for presetting the counter either synchronously or asynchronously. In normal operation, the counter is decremented by one count on each positive-going transition of the clock (CP). Counting is inhibited when the terminal enable input (TE) is HIGH. The terminal count output (TC) goes LOW when the count reaches zero if TE is LOW, and remains LOW for one full clock period. When the synchronous preset enable input (PE) is LOW, data at the jam input (P0 to P7) is clocked into the counter on the next positive-going clock transition regardless of the state of TE. When the asynchronous preset enable input (PL) is LOW, data at the jam input (P0 to P7) is asynchronously forced into the counter regardless of the state of PE, TE, or CP. The jam inputs (P0 to P7) represent a single 8-bit binary word. When the master reset input (MR) is LOW, the counter is asynchronously cleared to its maximum count (decimal 255) regardless of the state of any other input. If all control inputs except TE are HIGH at the time of zero count, the counters will jump to the maximum count, giving a counting sequence of 256 clock pulses long. Device may be cascaded using the TE input and the TC output, in either a synchronous or ripple mode. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Cascadable
- Synchronous or asynchronous preset
- Low-power dissipation
- Complies with JEDEC standard no. 7A
- CMOS input levels
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from −40 °C to +80 °C and from −40 °C to +125 °C

3. Applications

- Divide-by-n counters
- Programmable timers
- Interrupt timers
- Cycle/program counters.



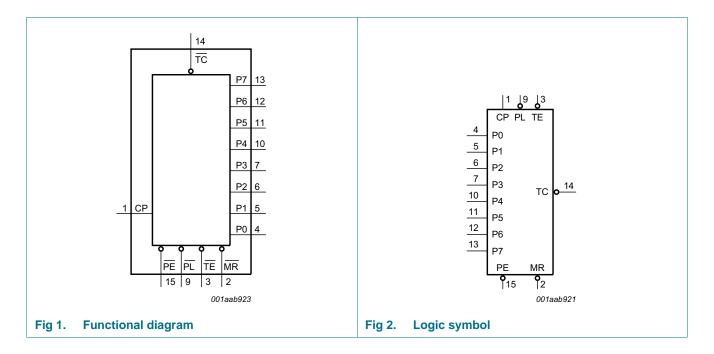
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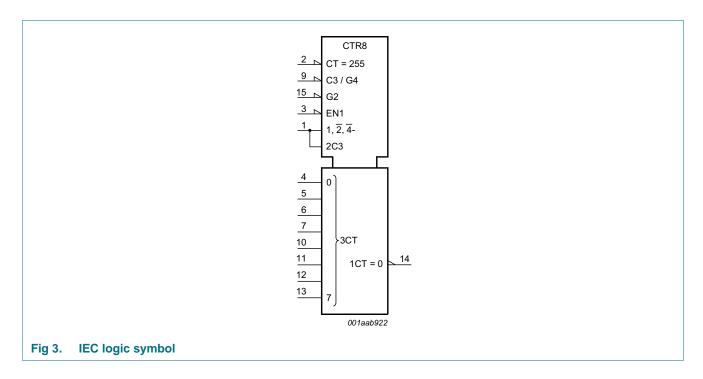
4. Ordering information

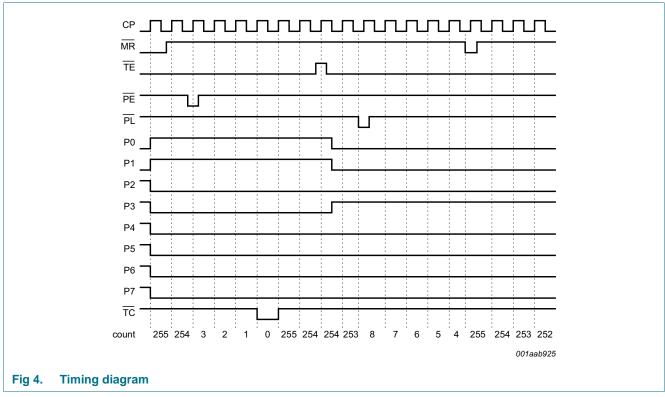
Table 1. Ordering information

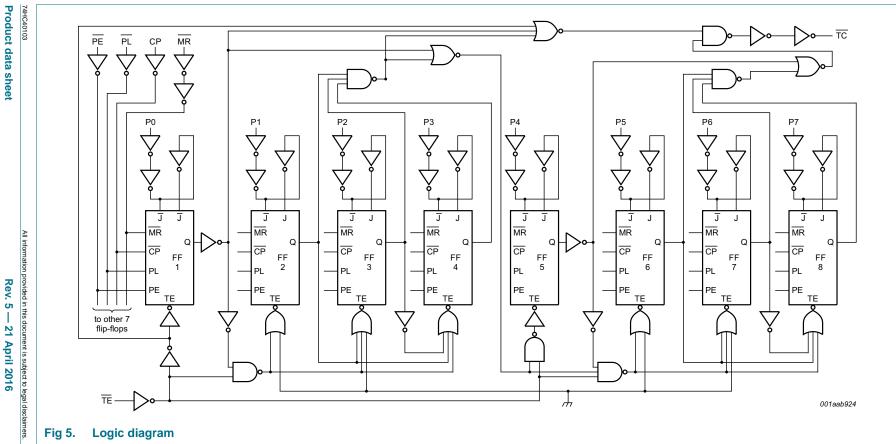
Type number	Package							
	Temperature range	Name	Description	Version				
74HC40103D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1				
74HC40103PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				

5. Functional diagram





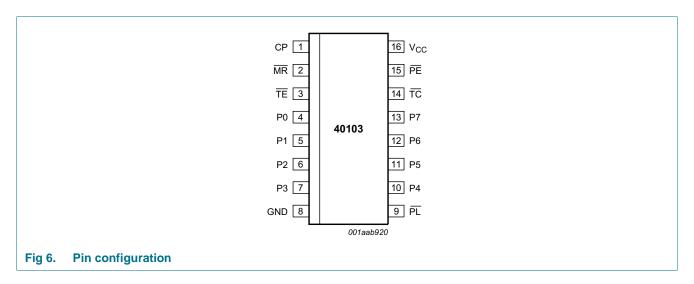




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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
СР	1	clock input (LOW-to-HIGH, edge-triggered)
MR	2	asynchronous master reset input (active LOW)
TE	3	terminal enable input (active LOW)
P0	4	jam input 0
P1	5	jam input 1
P2	6	jam input 2
P3	7	jam input 3
GND	8	ground (0 V)
PL	9	asynchronous preset enable input (active LOW)
P4	10	jam input 4
P5	11	jam input 5
P5	12	jam input 6
P7	13	jam input 7
TC	14	terminal count output (active LOW)
PE	15	synchronous preset enable input (active LOW)
V _{CC}	16	positive supply voltage

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7. Functional description

7.1 Function table

Table 3. Function table[1]

Contr	ol inputs			Preset mode	Action ^[2]
MR	PL	PE	TE		
L	Х	Х	Х	asynchronous	clear to maximum count
Н	H L X X		asynchronous	preset asynchronously	
	Н	L	Х	synchronous	preset on next LOW-to HIGH clock transition
	H L		synchronous	count down	
			Н	synchronous	inhibit counter

^[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

Synchronous operation: changes occur on the LOW-to-HIGH CP transition.

Jam inputs: MSD = P7, LSD = P0.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
Io	output current	$V_O = -0.5 \text{ V}$ to $V_{CC} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			- 65	+150	°C
P _{tot}	total power dissipation	SO16 package	[2]	-	500	mW
		TSSOP16 packages	<u>[3]</u>	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] Clock connected to CP.

^[2] For SO16 package: above 70 °C, Ptot derates linearly with 8 mW/K.

^[3] For TSSOP16 package: above 60 °C, Ptot derates linearly with 5.5 mW/K.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
Δt/ΔV	input transition rise and	V _{CC} = 2.0 V	-	-	625	ns
	fall rates	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	83	ns
T _{amb}	ambient temperature		-40	-	+125	°C

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V_{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	V	
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_{O} = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	V
		$I_{O} = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	V
		I _O = 4 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μΑ
C _I	input capacitance		-	3.5	-	pF

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 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40	0 °C to +85 °C		,			
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH}$ or V_{IL}				
		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	-	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	-	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.33	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
lcc	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	80	μΑ
Γ _{amb} = -40	0 °C to +125 °C		II.			
√ _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
/ _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
√oH	HIGH-level output voltage	$V_{I} = V_{IH}$ or V_{IL}				
		$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	-	-	V
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	-	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 \text{ V}$	5.9	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_O = -5.2 \text{ mA}$; $V_{CC} = 6.0 \text{ V}$	5.2	-	-	V

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 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	-	0.1	V
		$I_O = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μΑ

11. Dynamic characteristics

Table 7. Dynamic characteristics

 $GND = 0 \ V; \ t_r = t_f = 6 \ ns; \ C_L = 50 \ pF; \ see Figure 13.$

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	S °C					
t _{pd}	propagation delay	CP to TC; see Figure 7				
		V _{CC} = 2.0 V	-	96	300	ns
		V _{CC} = 4.5 V	-	35	60	ns
		V _{CC} = 6.0 V	-	28	51	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	30	-	ns
		TE to TC; see Figure 8				
		V _{CC} = 2.0 V	-	50	175	ns
		V _{CC} = 4.5 V	-	18	35	ns
		V _{CC} = 6.0 V	-	14	30	ns
		PL to TC; see Figure 9				
		V _{CC} = 2.0 V	-	102	315	ns
		V _{CC} = 4.5 V	-	37	63	ns
		V _{CC} = 6.0 V	-	30	53	ns
t _{PHL}	HIGH to LOW	MR to TC; see Figure 9				
	propagation delay	V _{CC} = 2.0 V	-	83	275	ns
		V _{CC} = 4.5 V	-	30	55	ns
		V _{CC} = 6.0 V	-	24	47	ns
t _t	transition time	see Figure 8 [2]				
		V _{CC} = 2.0 V	-	19	75	ns
		V _{CC} = 4.5 V	-	7	15	ns
		V _{CC} = 6.0 V	-	6	13	ns

Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 13</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _W	pulse width	CP HIGH or LOW; see Figure 7				
		V _{CC} = 2.0 V	165	22	-	ns
		V _{CC} = 4.5 V	33	8	-	ns
		V _{CC} = 6.0 V	28	6	-	ns
		MR LOW; see Figure 9				
		V _{CC} = 2.0 V	125	39	-	ns
		V _{CC} = 4.5 V	25	14	-	ns
		V _{CC} = 6.0 V	21	11	-	ns
		PL LOW; see Figure 9				
		V _{CC} = 2.0 V	125	33	-	ns
		V _{CC} = 4.5 V	25	12	-	ns
		V _{CC} = 6.0 V	21	10	-	ns
t _{rec}	recovery time	MR to CP, PL to CP; see Figure 10				
		V _{CC} = 2.0 V	50	14	-	ns
		V _{CC} = 4.5 V	10	5	-	ns
		V _{CC} = 6.0 V	9	4	-	ns
t _{su}	set-up time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	75	22	-	ns
		$V_{CC} = 4.5 \text{ V}$ 15	15	8	-	ns
		V _{CC} = 6.0 V	13	6	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	150	44	-	ns
		V _{CC} = 4.5 V	30	16	-	ns
		V _{CC} = 6.0 V	26	13	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	75	22	-	ns
		V _{CC} = 4.5 V	15	8	-	ns
		V _{CC} = 6.0 V	13	6	-	ns
t _h	hold time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-14	-	ns
		V _{CC} = 4.5 V	0	-5	-	ns
		V _{CC} = 6.0 V	0	-4	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	0	-30	-	ns
		V _{CC} = 4.5 V	0	-11	-	ns
		V _{CC} = 6.0 V	0	-9	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-17	-	ns
		V _{CC} = 4.5 V	0	-6	-	ns
		V _{CC} = 6.0 V	0	-5	-	ns

Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 13</u>.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
f _{max}	maximum frequency	see Figure 7					
		V _{CC} = 2.0 V		3.0	10	-	MHz
		V _{CC} = 4.5 V		15	29	-	MHz
		V _{CC} = 6.0 V		18	35	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF		-	32	-	MHz
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}$	[3]	-	24	-	pF
$T_{amb} = -4$	0 °C to +85 °C		•			*	
t _{pd}	propagation delay	CP to TC; see Figure 7	<u>[1]</u>				
		V _{CC} = 2.0 V		-	-	375	ns
		V _{CC} = 4.5 V		-	-	75	ns
		V _{CC} = 6.0 V		-	-	64	ns
		TE to TC; see Figure 8					
		V _{CC} = 2.0 V		-	-	220	ns
		V _{CC} = 4.5 V		-	-	44	ns
		V _{CC} = 6.0 V		-	-	37	ns
		PL to TC; see Figure 9					
		V _{CC} = 2.0 V		-	-	395	ns
		V _{CC} = 4.5 V		-	-	79	ns
		V _{CC} = 6.0 V		-	-	40	ns
t _{PHL}	HIGH to LOW	MR to TC; see Figure 9					
	propagation delay	V _{CC} = 2.0 V		-	-	345	ns
		V _{CC} = 4.5 V		-	-	69	ns
		V _{CC} = 6.0 V		-	-	59	ns
t _t	transition time	see Figure 8	[2]				
		V _{CC} = 2.0 V		-	-	95	ns
		V _{CC} = 4.5 V		-	-	19	ns
		V _{CC} = 6.0 V		-	-	16	ns
t _W	pulse width	CP HIGH or LOW; see Figure 7					
		V _{CC} = 2.0 V		205	-	-	ns
		V _{CC} = 4.5 V		41	-	-	ns
		V _{CC} = 6.0 V		35	-	-	ns
		MR LOW; see Figure 9					
		V _{CC} = 2.0 V		155	-	-	ns
		V _{CC} = 4.5 V		31	-	-	ns
		V _{CC} = 6.0 V		26	-	-	ns
		PL LOW; see Figure 9					
		V _{CC} = 2.0 V		155	-	-	ns
		V _{CC} = 4.5 V		31	-	-	ns
		V _{CC} = 6.0 V		26	-	-	ns

Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 13</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
rec	recovery time	MR to CP, PL to CP; see Figure 10				
		V _{CC} = 2.0 V	65	-	-	ns
		V _{CC} = 4.5 V	13	-	-	ns
		V _{CC} = 6.0 V	11	-	-	ns
su	set-up time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	95	-	-	ns
		V _{CC} = 4.5 V	19	-	-	ns
		V _{CC} = 6.0 V	16	-	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	190	-	-	ns
		V _{CC} = 4.5 V	38	-	-	ns
		V _{CC} = 6.0 V	33	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	95	-	-	ns
		V _{CC} = 4.5 V	19	-	-	ns
		V _{CC} = 6.0 V	16	-	-	ns
ı	hold time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
nax	maximum frequency	see Figure 7				
		V _{CC} = 2.0 V	2.4	-	-	MHz
		V _{CC} = 4.5 V	12	-	-	MHz
		V _{CC} = 6.0 V	14	-	-	MHz

Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 13</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	10 °C to +125 °C					
t _{pd} propagation delay		CP to TC; see Figure 7	[1]			
		V _{CC} = 2.0 V	-	-	450	ns
		V _{CC} = 4.5 V	-	-	90	ns
		V _{CC} = 6.0 V	-	-	77	ns
		TE to TC; see Figure 8				
		V _{CC} = 2.0 V	-	-	265	ns
		V _{CC} = 4.5 V	-	-	53	ns
		V _{CC} = 6.0 V	-	-	45	ns
		PL to TC; see Figure 9				
		V _{CC} = 2.0 V	-	-	475	ns
		V _{CC} = 4.5 V	-	-	95	ns
		V _{CC} = 6.0 V	-	-	81	ns
t _{PHL}	HIGH to LOW	MR to TC; see Figure 9				
	propagation delay	V _{CC} = 2.0 V	-	-	415	ns
	V _{CC} = 4.5 V	-	-	83	ns	
		V _{CC} = 6.0 V	-	-	71	ns
t _t	transition time	see Figure 8	[2]			
		V _{CC} = 2.0 V	-	-	110	ns
		V _{CC} = 4.5 V	-	-	22	ns
		V _{CC} = 6.0 V	-	-	19	ns
t _W	pulse width	CP HIGH or LOW; see Figure 7				
		V _{CC} = 2.0 V	250	-	-	ns
		V _{CC} = 4.5 V	50	-	-	ns
		V _{CC} = 6.0 V	43	-	-	ns
		MR LOW; see Figure 9				
		V _{CC} = 2.0 V	190	-	-	ns
		V _{CC} = 4.5 V	38	-	-	ns
		V _{CC} = 6.0 V	32	-	-	ns
		PL LOW; see Figure 9				
		V _{CC} = 2.0 V	190	-	-	ns
		V _{CC} = 4.5 V	38	-	-	ns
		V _{CC} = 6.0 V	32	-	-	ns
t _{rec}	recovery time	MR to CP, PL to CP; see Figure 10				
		V _{CC} = 2.0 V	75	-	-	ns
		V _{CC} = 4.5 V	15	-	-	ns
		V _{CC} = 6.0 V	13	-	-	ns

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Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 13</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
set-up time	PE to CP; see Figure 11					
		V _{CC} = 2.0 V	110	-	-	ns
		V _{CC} = 4.5 V	22	-	-	ns
		V _{CC} = 6.0 V	19	-	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	225	-	-	ns
		V _{CC} = 4.5 V	45	-	-	ns
		V _{CC} = 6.0 V	38	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	110	-	-	ns
		V _{CC} = 4.5 V	22	-	-	ns
		V _{CC} = 6.0 V	19	-	-	ns
h	hold time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
		TE to CP; see Figure 12				
	V _{CC} = 2.0 V	0	-	-	ns	
	V _{CC} = 4.5 V	0	-	-	ns	
		V _{CC} = 6.0 V	0	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
: max	maximum frequency	see Figure 7				
		V _{CC} = 2.0 V	2.0	-	-	MHz
		V _{CC} = 4.5 V	10	-	-	MHz
		V _{CC} = 6.0 V	12	-	-	MHz

- [1] t_{pd} is the same as t_{PHL} , t_{PLH} .
- [2] t_t is the same as t_{THL} , t_{TLH} .
- [3] $\,$ $\,$ C_{PD} is used to determine the dynamic power dissipation (P_D in $\mu W).$

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

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12. Waveforms

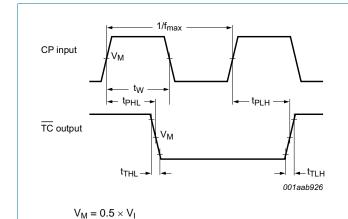
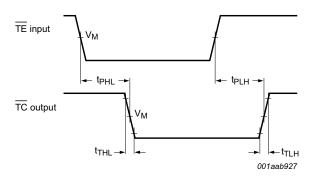


Fig 7. Waveforms showing the clock input (CP) to TC propagation delays, the clock pulse width, the output transition times and the maximum clock pulse frequency



 $V_M = 0.5 \times V_I$

Fig 8. Waveforms showing the TE to TC propagation delays

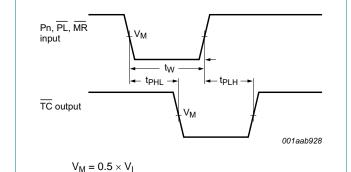
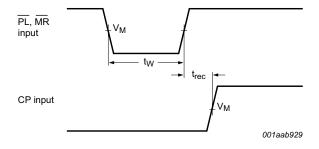


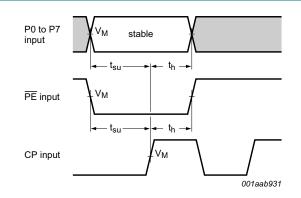
Fig 9. Waveforms showing PL, MR, Pn to TC propagation delays



 $V_{M}=0.5\times V_{I}$

Fig 10. Waveforms showing removal time for MR and

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The shaded areas indicate when the input is permitted to change for predictable output performance.

 $V_M = 0.5 \times V_I$

Fig 11. Waveforms showing hold and set-up times for Pn, PE to CP

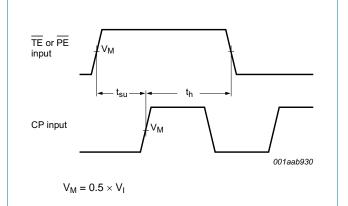
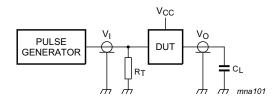


Fig 12. Waveforms showing hold and set-up times for MR or PE to CP



Test data is given in Table 8.

Definitions for test circuit:

 R_{T} = Termination resistance should be equal to output impedance Z_{0} of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

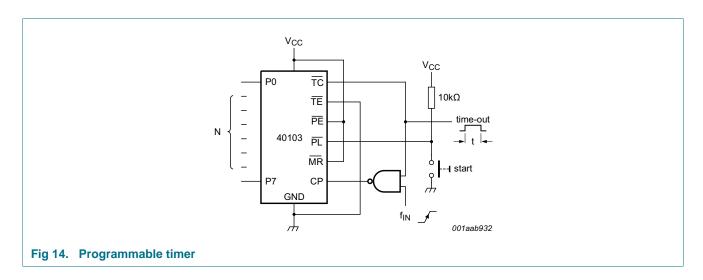
Fig 13. Test circuit for measuring switching times

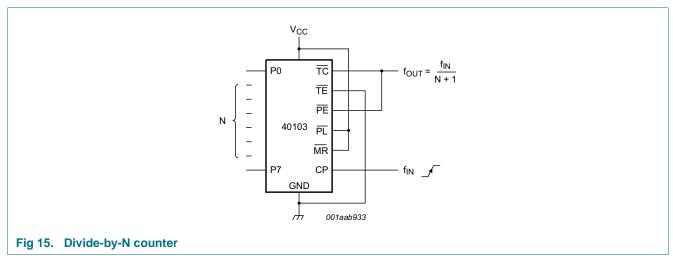
Table 8. Test data

Supply	Input	Load	
V _{CC}	V _I	t _r , t _f	CL
2.0 V	V _{CC}	6 ns	50 pF
4.5 V	V _{CC}	6 ns	50 pF
6.0 V	V _{CC}	6 ns	50 pF
5.0 V	V _{CC}	6 ns	15 pF

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13. Application information



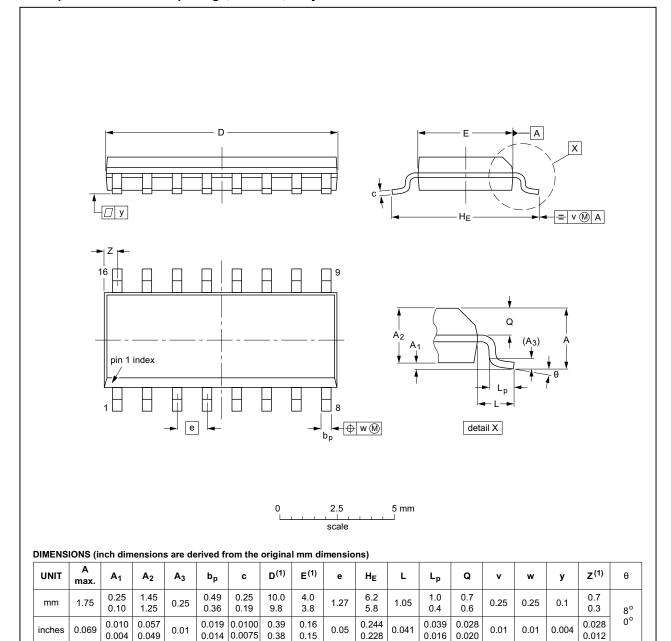


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14. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DA			
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE		
SOT109-1	076E07	MS-012			99-12-27 03-02-19		

Fig 16. Package outline SOT109-1 (SO16)

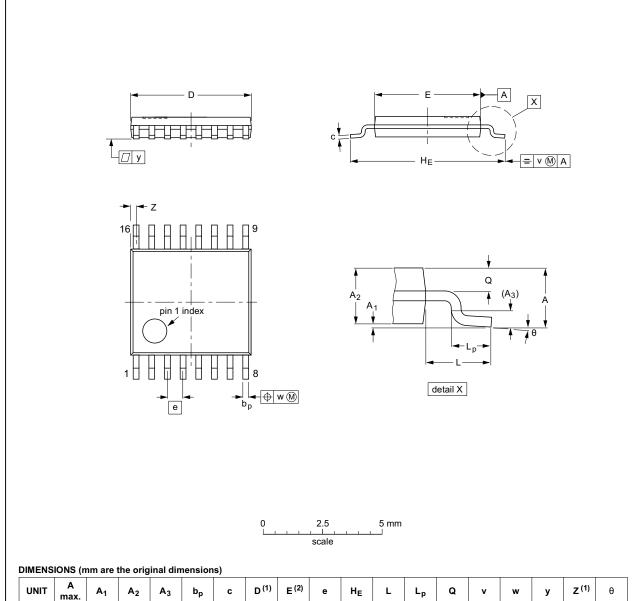
74HC40103

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	REFER	RENCES	EUROPEAN ISSUE D		
IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
	MO-153			99-12-27 03-02-18	
-	IEC	IEC JEDEC	IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION	

Fig 17. Package outline SOT403-1 (TSSOP16)

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15. Abbreviations

Table 9. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

16. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC40103 v.5	20160421	Product data sheet	-	74HC40103 v.4			
Modifications:	Type numb	er 74HC40103DB (SOT338-1)	removed.				
74HC40103 v.4	20160127	Product data sheet	-	74HC40103 v.3			
Modifications:	Type number 74HC40103N (SOT38-4) removed.						
74HC40103 v.3	20041112	Product data sheet	-	74HC_HCT40103_CNV v.2			
Modifications:		 The format of this data sheet has been redesigned to comply with the current presentation and information standard of Philips Semiconductors. 					
	 Removed t 	Removed type number 74HCT40103.					
	Inserted family specification.						
74HC_HCT40103_CNV v.2	19970918	Product specification	-	74HC_HCT40103 v.1			
74HC_HCT40103 v.1	19901201	Product specification	-	-			

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17. Legal information

17.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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